TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

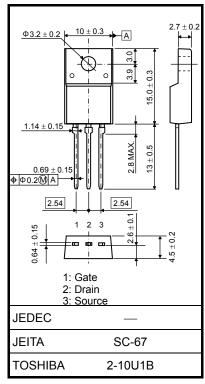
TK11A45D

Switching Regulator Applications

- Low drain-source ON-resistance: $RDS(ON) = 0.5 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 3.2 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 450 \ V)$
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Characteristics			Symbol	Rating	Unit	
Drain-source voltage			V _{DSS}	450	V	
Gate-source voltage			V _{GSS}	±30	V	
Drain current	DC (1	Note 1)	Ι _D	11	А	
	Pulse (1	Note 1)	I _{DP}	44	A	
Drain power dissipation (Tc = 25° C)			PD	40	W	
Single pulse avalanche energy (Note 2)			E _{AS}	238	mJ	
Avalanche current			I _{AR}	11	А	
Repetitive avalanche energy (Note 3)			E _{AR}	4.0	mJ	
Channel temperature			T _{ch}	150	°C	
Storage temperature range			T _{stg}	-55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

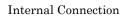
Thermal Characteristics

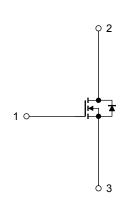
Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 3.27 mH, R_G = 25 Ω , I_{AR} = 11 A

This transistor is an electrostatic-sensitive device. Handle with care.





Start of commercial production 2009-09

Unit: mm

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

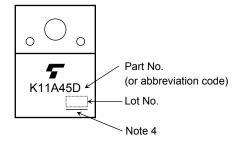
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$			±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 450 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	450		_	V
Gate threshold voltage		V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	l-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5.5 \text{ A}$		0.5	0.62	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5.5 \text{ A}$	0.8	3.2	_	S
Input capacitance		C _{iss}		_	1050	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		5	_	pF
Output capacitance		C _{oss}	1		100	_	
Switching time	Rise time	tr	V_{GS}		25		
	Turn-on time	t _{on}	$\begin{array}{c} & & \\$		60		. ns
	Fall time	t _f	// V _{DD} ≈ 200 V		10	_	
	Turn-off time	t _{off}	Duty \leq 1%, t _W = 10 μ s	—	75	_	
Total gate charge		Qg			20		
Gate-source charge		Q _{gs}	$V_{DD} \approx 360 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 11 \text{ A}$		13		nC
Gate-drain charge		Q _{gd}]		7		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	11	А
Pulse drain reverse current (Note 1)	I _{DRP}	—		_	44	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 11 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 11 \text{ A}, V_{GS} = 0 \text{ V},$		1350		ns
Reverse recovery charge	Qrr	dl _{DR} /dt = 100 A/μs	_	14	_	μC

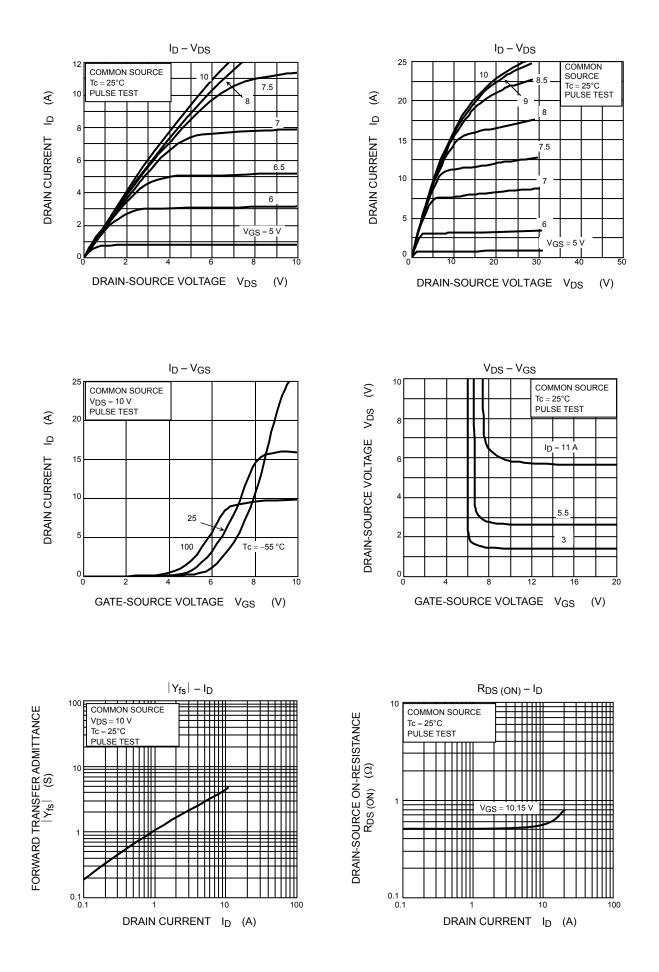
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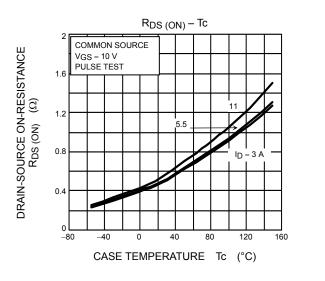
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

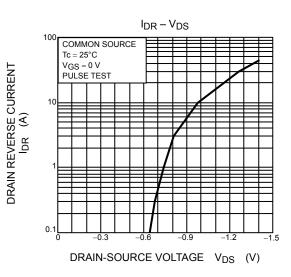
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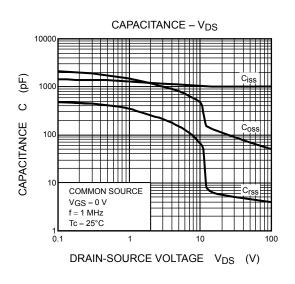
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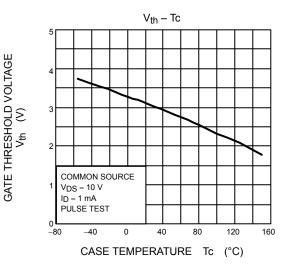


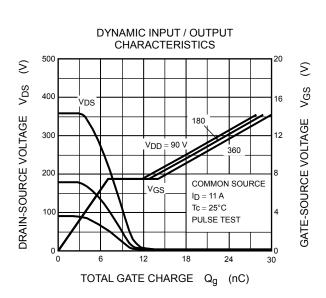
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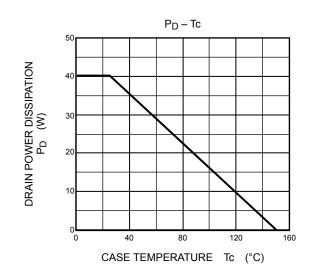


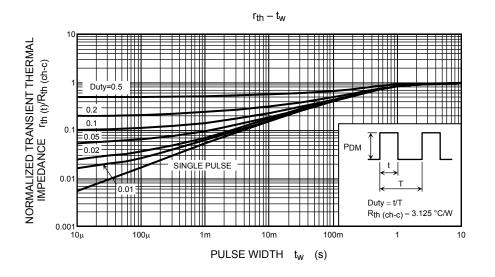




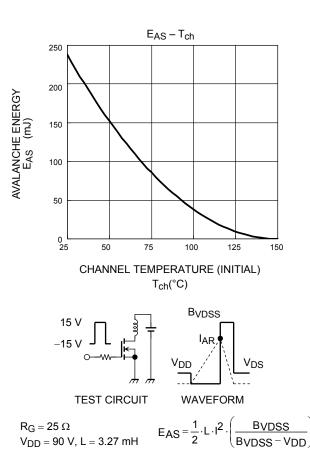








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